

TOSHIBA Transistor Silicon PNP Epitaxial Type

## 2SA2097

High-Speed Switching Applications

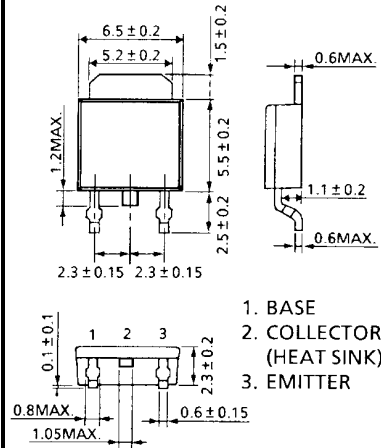
DC-DC Converter Applications

Unit: mm

- High DC current gain:  $h_{FE} = 200$  to  $500$  ( $I_C = -0.5$  A)
- Low collector-emitter saturation:  $V_{CE(sat)} = -0.27$  V (max)
- High-speed switching:  $t_f = 55$  ns (typ.)

Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

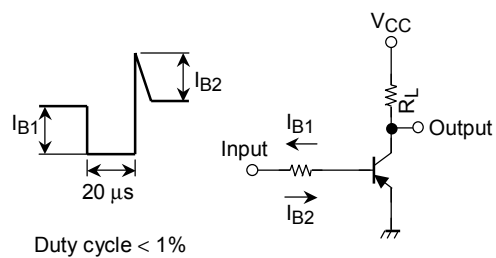
| Characteristics             |                          | Symbol    | Rating     | Unit             |
|-----------------------------|--------------------------|-----------|------------|------------------|
| Collector-base voltage      |                          | $V_{CBO}$ | -50        | V                |
| Collector-emitter voltage   |                          | $V_{CEO}$ | -50        | V                |
| Emitter-base voltage        |                          | $V_{EBO}$ | -7         | V                |
| Collector current           | DC                       | $I_C$     | -5         | A                |
|                             | Pulse                    | $I_{CP}$  | -10        |                  |
| Base current                |                          | $I_B$     | -0.5       | A                |
| Collector power dissipation | $T_a = 25^\circ\text{C}$ | $P_c$     | 1          | W                |
|                             | $T_c = 25^\circ\text{C}$ |           | 20         |                  |
| Junction temperature        |                          | $T_j$     | 150        | $^\circ\text{C}$ |
| Storage temperature range   |                          | $T_{stg}$ | -55 to 150 | $^\circ\text{C}$ |

|   |        |
|---|--------|
|  |        |
| JEDEC   | —      |
| JEITA   | SC-64  |
| TOSHIBA   | 2-7J1A |

Weight: 0.36 g (typ.)

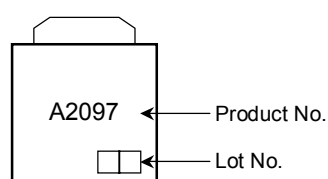
Electrical Characteristics ( $T_a = 25^\circ\text{C}$ )

| Characteristics                      |              | Symbol         | Test Condition  | Min | Typ. | Max   | Unit |
|--------------------------------------|--------------|----------------|---|-----|------|-------|------|
| Collector cut-off current            |              | $I_{CBO}$      | $V_{CB} = -50$ V, $I_E = 0$   | —   | —    | -100  | nA   |
| Emitter cut-off current              |              | $I_{EBO}$      | $V_{EB} = -7$ V, $I_C = 0$  | —   | —    | -100  | nA   |
| Collector-emitter brakedown voltage  |              | $V_{(BR) CEO}$ | $I_C = -10$ mA, $I_B = 0$   | -50 | —    | —     | V    |
| DC current gain                      |              | $h_{FE} (1)$   | $V_{CE} = -2$ V, $I_C = -0.5$ A   | 200 | —    | 500   |      |
|                                      |              | $h_{FE} (2)$   | $V_{CE} = -2$ V, $I_C = -1.6$ A   | 100 | —    | —     |      |
| Collector-emitter saturation voltage |              | $V_{CE(sat)}$  | $I_C = -1.6$ A, $I_B = -53$ mA  | —   | —    | -0.27 | V    |
| Base-emitter saturation voltage      |              | $V_{BE(sat)}$  | $I_C = -1.6$ A, $I_B = -53$ mA  | —   | —    | -1.10 | V    |
| Switching time                       | Rise time    | $t_r$          | See Figure 1 circuit diagram<br>$V_{CC} = -24$ V, $R_L = 15\ \Omega$<br>$I_{B1} = -I_{B2} = -53$ mA | —   | 63   | —     | ns   |
|                                      | Storage time | $t_{stg}$      |   | —   | 280  | —     |      |
|                                      | Fall time    | $t_f$          |   | —   | 55   | —     |      |

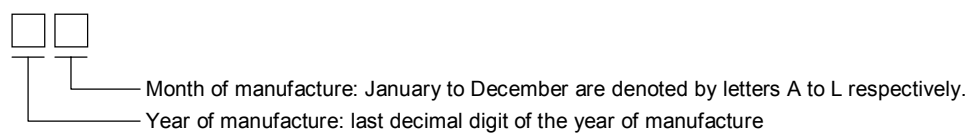


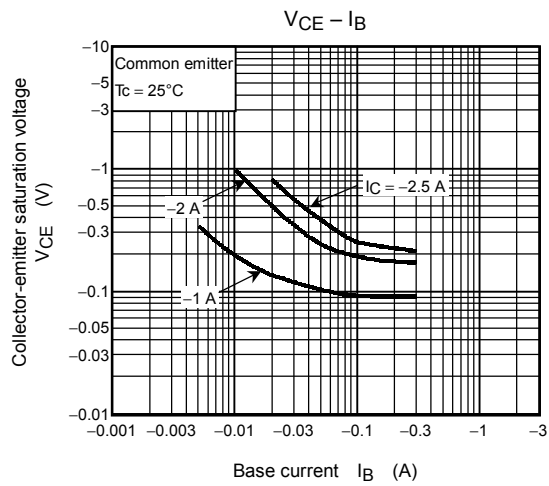
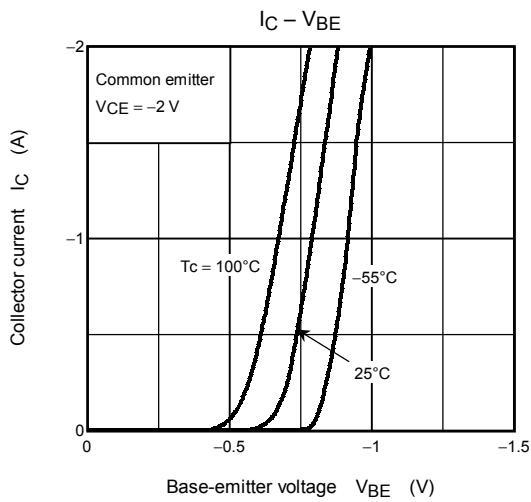
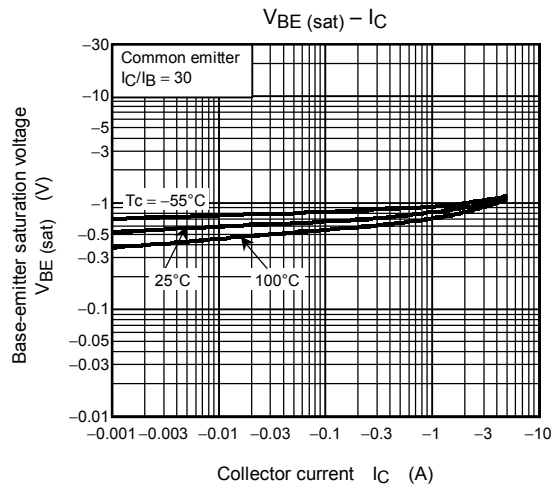
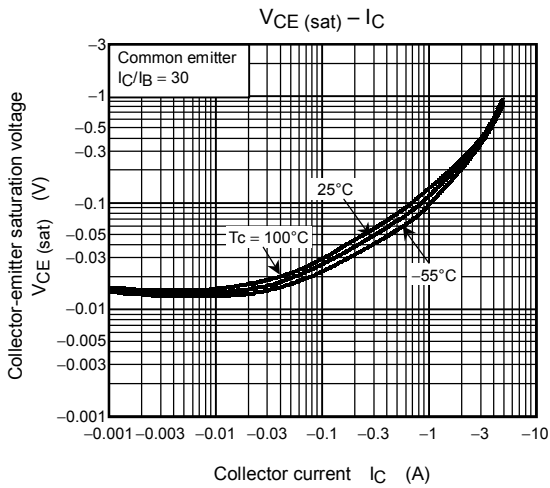
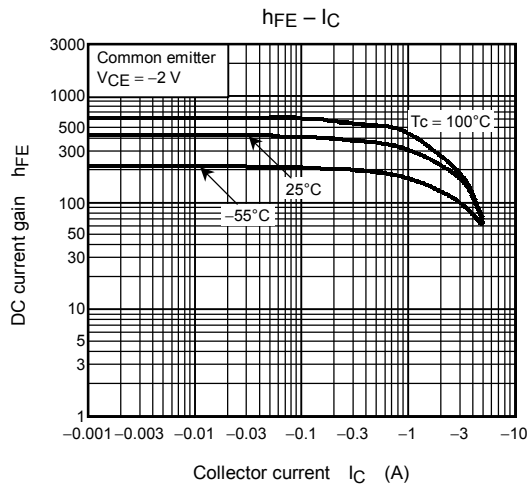
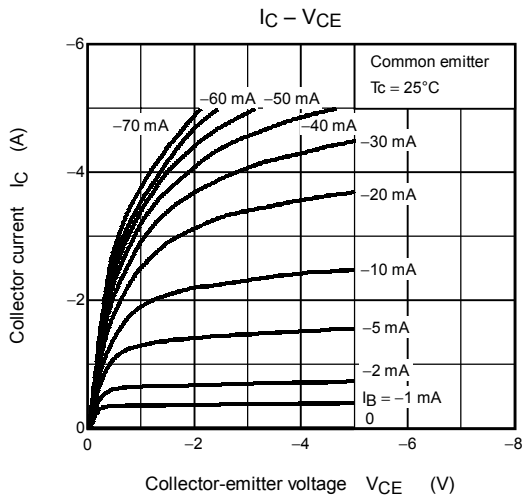
**Figure 1 Switching Time Test Circuit & Timing Chart**

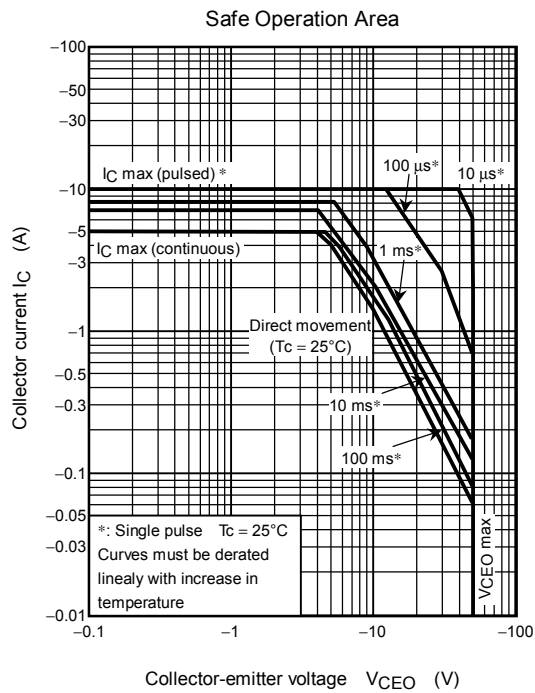
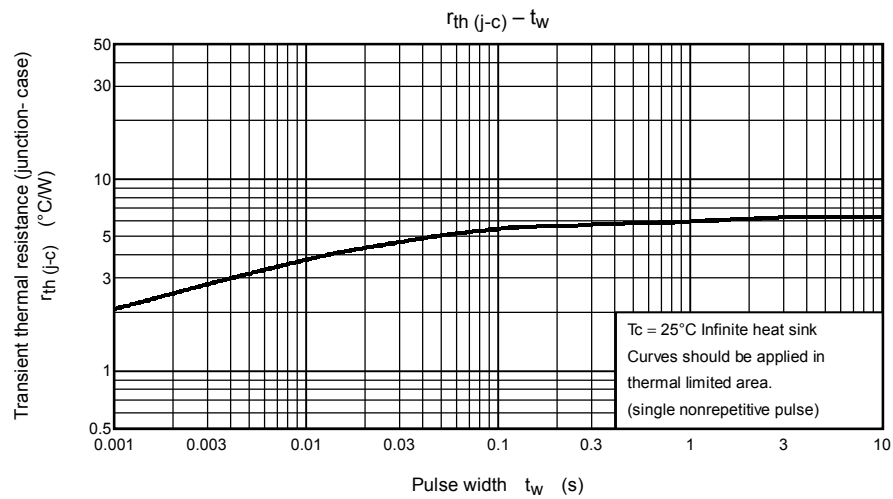
## Marking



## Explanation of Lot No.







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